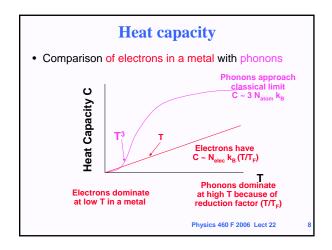


<b>Typical values for electrons</b>			
Here we count only valence electrons (see Kittel table)			
Element	N <sub>elec</sub> /atom	$E_F$	$T_F = E_F/k_B$
Li	1	4.7 eV	5.5 x10 <sup>4</sup> K
Na	1	3.23eV	3.75 x10⁴ K
Al	3	11.6 eV	13.5 x10 <sup>4</sup> K
Conclusion: For typical metals the Fermi energy (or the Fermi temperature) is much greater than ordinary temperatures			
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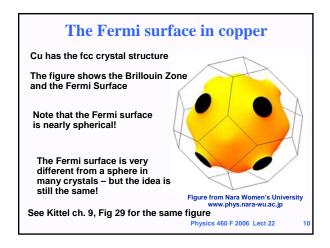
# Heat Capacity for Electrons • Just as for phonons the definition of heat capacity is C = dU/dT where U = total internal energy • For T < T<sub>F</sub> = E<sub>F</sub>/k<sub>B</sub> it is easy to see that roughly U ~ U0 + N<sub>elec</sub> (T/T<sub>F</sub>) k<sub>B</sub> T so that C = dU/dT ~ N<sub>elec</sub> k<sub>B</sub> (T/T<sub>F</sub>) 1 Chemical potential for electrons D(E) Physics 460 F 2006 Lect 22 7



#### What about a real metal?

- In a crystal the energies are not  $E = (h^2/2m) k^2$
- Instead the energy is E<sub>n</sub>(k), where k is the wavevector in the Brillouin Zone, and n = 1,2,3,... labels the bands
- The energy E<sub>n</sub>(k) is different for k in different directions
- The concepts still apply 
  The states are filled for  $E_n(\mathbf{k}) < E_{Fermi}$  
  The states are empty for  $E_n(\mathbf{k}) > E_{Fermi}$
- This defines the Fermi surface: the surface in k-space where  $E_n(\mathbf{k}) < E_{\text{Fermi}}$  the boundary between filled and empty states

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#### **Heat capacity**

- Experimental results for metals  $C/T = \gamma + A T^2 + ...$
- It is most informative to find the ratio  $\gamma$  /  $\gamma$ (free) where  $\gamma$ (free) =  $(\pi^2/2)$  ( $N_{\rm elec}/E_{\rm F}$ )  $k_{\rm B}^2$  is the free electron gas result. Equivalently since  $E_{\rm F} \propto 1/m$ , we can consider the ratio  $\gamma$  /  $\gamma$ (free) = m(free)/ $m_{\rm th}^*$ , where  $m_{\rm th}^*$  is an thermal effective mass for electrons in the metal

 $\begin{array}{lll} \text{Metal} & & \text{m}_{\text{th}}{}^{*}/\,\text{m(free)} \\ \text{Li} & & 2.18 \\ \text{Na} & & 1.26 \\ \text{K} & & 1.25 \\ \text{Al} & & 1.48 \\ \text{Cu} & & 1.38 \\ \end{array}$ 

• m<sub>th</sub>\* close to m(free) is the "good", "simple metals" !

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#### **Electrical Conductivity & Ohm's Law**

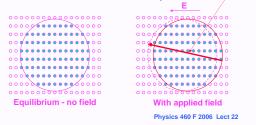
- Consider electrons in an external field E. They experience a force F = -eE
- Now  $F = dp/dt = \hbar dk/dt$ , since  $p = \hbar k$
- Thus in the presence of an electric field all the electrons accelerate and the k points shift, i.e., the entire Fermi surface shifts

Equilibrium - no field

The same ideas apply to real metals with non-spherical Fermi surfaces

#### Electrical Conductivity & Ohm's Law · What limits the acceleration of the electrons?

- Scattering increases as the electrons deviate more from equilibrium
- After field is applied a new equilibrium results as a balance between acceleration by field and scattering



#### **Electrical Conductivity and Resistivity**

- The conductivity  $\sigma$  is defined by  $j = \sigma E$ , where i = current density
- How to find σ?
- From before  $F = dp/dt = m dv/dt = \hbar dk/dt$
- Equilibrium is established when the rate that k increases due to E equals the rate of decrease due to scattering, then dk/dt = 0
- If we define a scattering time  $\tau$  and scattering rate  $1/\tau$  $\hat{h}$  ( dk/dt + k / $\tau$  ) = F= q E (q = charge)
- Now j = n q v (where n = density) so that  $j = n q (h k/m) = (n q^2/m) \tau E$
- $\Rightarrow$   $\sigma = (n q^2/m) \tau$ • Resistance:  $\rho$  = 1/  $\sigma$   $\propto$  m/(n  $q^2$   $\tau$ )

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#### **Scattering mechanisms**

· Impurities - wrong atoms, missing atoms, extra atoms,

Proportional to concentration

• Lattice vibrations - atoms out of their ideal places

Proportional to mean square displacement

• (Really these conclusions depend upon ideas from the next section that there is no scattering in a perfect crystal.)

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#### **Electrical Resistivity**

• Resistivity  $\rho$  is due to scattering: Scattering rate inversely proportional to scattering time t

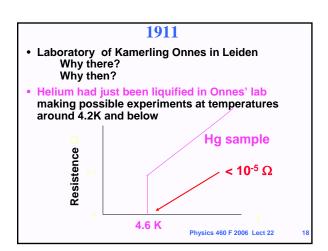
 $\rho \propto \text{scattering rate} \propto 1/\tau$ 

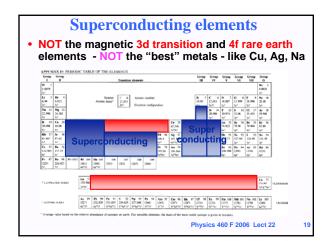
· Matthiesson's rule - scattering rates add

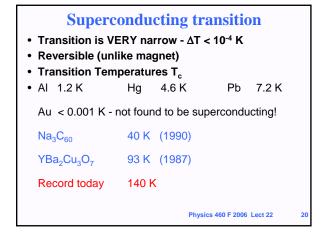
 $\rho = \rho_{\text{vibration}} + \rho_{\text{impurity}} \propto 1/\tau_{\text{vibration}} + 1/\tau_{\text{impurity}}$ Temperature independent Temperature dependent - sample dependent  $\infty < u^2 >$ 

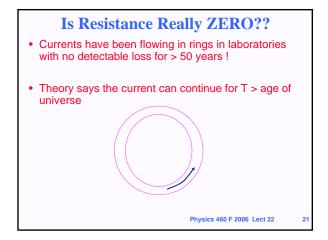
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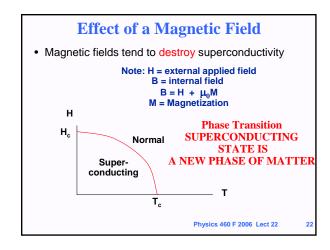
#### **Electrical Resitivity** Consider relative resistance R(T)/R(T=300K) · Typical behavior (here for potassium) Relative resistence Phonons dominate at high T because mean square 0.05 displacements <u²> ∞ T Leads to R ∝ T (Sample independent) Increase as T2 0.01 Т Inpurity scattering dominates at low T in a metal (Sample dependent) Physics 460 F 2006 Lect 22

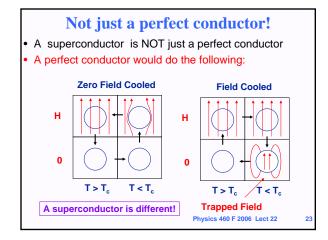


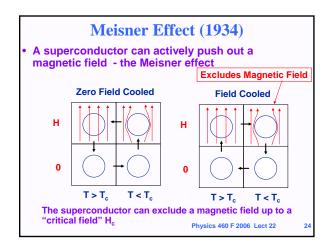


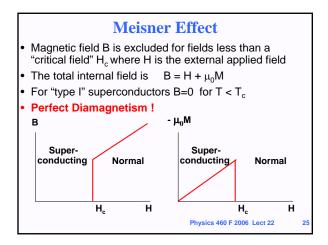


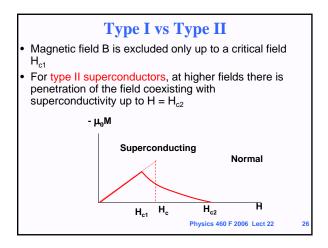


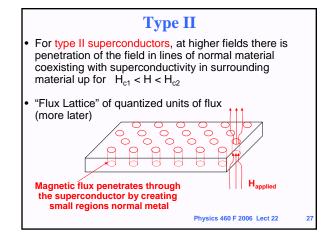


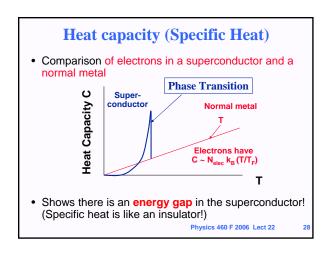




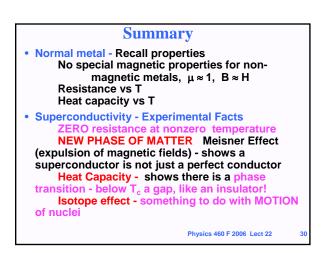








# Isotope Effect (1950) • For materials made from the same elements - but different isotopes - T<sub>c</sub> changes! • Experiment - T<sub>c</sub> ~ 1/ M<sup>1/2</sup> • MUST be connected to MOTION of the nuclei



#### **Next time**

- Superconductivity theory
   Basic ideas and phenomena
   Bardeen- Cooper-Schrieffer Theory 1957
   (Nobel Prize for work done in UIUC Physics)
- (Kittel parts of Ch 10)

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